### **Supporting Information for**

# **Encapsulation of Crystalline and Amorphous Sb2S<sup>3</sup> within Carbon and Boron Nitride Nanotubes**

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### **1. Materials and Methods**

**General Methods.** Structures were generated in SingleCrystal 4 software (CrystalMaker® Software Suite). Carbon nanotubes were generated in Avogadro: an open-source molecular builder and visualization tool. Version 1.2.0. http://avogadro.cc/ $\cdot$ <sup>1</sup> while boron nitride nanotubes were generated in VMD.<sup>2</sup> Calibrated optical images of representative crystals were taken with a Google Pixel 6. All figures were lay-outed and processed in Lunacy.

**Synthesis of bulk Sb2S<sup>3</sup> Precursors.** Elemental precursors of antimony (99.5 %) and sulfur (99+%) were purchased from STREM and used without further purification. Bulk Sb<sub>2</sub>S<sub>3</sub> crystals that were used as precursors for subsequent syntheses were grown as follows: Stoichiometric quantities of Sb and S (2:3 ratio) were evacuated in quartz ampoules (10 mm I.D.; 12 mm O.D.) under a <50 mTorr base pressure and were subsequently flame sealed. The ampoules were then uniformly heated to 600 °C for 96 hours in a single-zone vertical tube furnace (OTF-1200F; MTI Inc.) then cooled over the course of 48 hours. The phase purity of the  $Sb_2S_3$  polycrystals were confirmed by powder X-ray diffraction (PXRD) on a Rigaku MiniFlex diffractometer (**Fig. S1**). The resulting diffractogram was compared to the reported literature structure.<sup>3</sup>

**Encapsulation of Sb2S<sup>3</sup> within SWCNTs, MWCNTs, & BNNTs.** High purity single-walled carbon nanotubes  $(1.6 \pm 0.4$  nm diameter, Tuball, OCSiAl) were opened by heating the as-received nanotubes at 420 °C in ambient air conditions for five hours. 10-20 nm multi-walled carbon nanotubes (Cheap Tubes Inc.) were heat treated at 420 <sup>o</sup>C for five to ten hours. Purified and treated (to open the ends) boron nitride nanotubes (BNNT LLC) were filled with  $Sb_2S_3$  without an oxidation step. A calcination step at 800 °C or stirring in aqua regia (3:1 conc. HCl/conc. HNO3) was found to make no considerable difference. Approximately 5 mg of these pre-treated NTs were then loaded into quartz ampoules immediately after heat treatment (10 mm I.D.; 12 mm O.D.) and mixed with a large excess of powdered  $Sb_2S_3$  polycrystals, ranging from 200 to 300 mg. Ampoules containing NTs and  $Sb_2S_3$  powders were evacuated under vacuum <50 mTorr and were immediately flame sealed. The ampoules were then heated to 600 °C for 96 hours in a single-zone vertical tube furnace (OTF-1200F; MTI Inc.) then cooled over the course of 48 hours. After the reaction, the  $Sb_2S_3@NTs$  were found to have phase separated from the  $Sb_2S_3$  melt. The  $Sb_2S_3@NTs$  were physically isolated from the resulting  $Sb_2S_3$  boule and were used in the succeeding experiments without further purification. Prior to ensemble measurements, the as-synthesized samples were washed and purified using isopropanol *via* a mixture of gentle pipetting, vortex mixing, and bath sonication and dried in a vacuum oven at 80 °C for at least one hour.

**High-resolution transmission electron microscopy (HRTEM), scanning transmission electron microscopy (STEM), and elemental mapping.** The resulting  $Sb_2S_3@NT$  heterostructures were dispersed in isopropanol *(i*-PrOH, 99.8%, Fisher Scientific) first gently suspending manually by pipetting several times before bath sonication for 5 mins, then drop-casted onto lacey carbon grids (Lacey Formvar/Carbon, 200 mesh, Cu grid; Ted Pella, Inc.) HRTEM images were acquired using a JEOL JEM-2800 S/TEM operated at an accelerating voltage of 200 kV equipped with a Gatan OneView 4K camera with drift correction. EDS mapping of  $Sb_2S_3@BNNTs$  was performed with the same microscope in STEM mode using dual  $100 \text{ mm}^2$  Si drift detectors.  $C_s$ -corrected scanning transmission electron microscopy (STEM) images and energy-dispersive X-ray spectra (EDS) of Sb<sub>2</sub>S<sub>3</sub>@SWCNTs was collected using a JEOL JEM-ARM300F Grand Arm electron microscope also equipped with dual 100 mm<sup>2</sup> Si drift detectors operated at 80 kV. Post-processing and image analyses of raw HRTEM and STEM data (.dm4) were done in Digital Micrograph (Gatan). Fast Fourier transform (FFT) analyses of the micrographs were done in Fiji.<sup>4</sup> Indexing of the FFT data were performed by comparing the experimental patterns with simulated patterns of the bulk single crystal structure using the SingleCrystal 4 software (CrystalMaker® Software Suite). HRTEM images were simulated using clTEM. 5

**Raman Spectroscopy.** Raman spectra were collected on a Horiba LabRAM HR Evolution with a 532 nm laser. Samples were prepared by dispersing Sb<sub>2</sub>S<sub>3</sub>@NTs in *i*-PrOH, sonicating for 5 to 20 mins, then drop-casting onto SiO2/Si substrate. Carbon nanotube G-bands were assessed by peak fitting in MagicPlot Pro with two Lorentzian peaks and a spline background. Peak maxima of filled and empty MWCNTs and SWCNTs were extracted and compared. The broadening of the G-bands was assessed by extracting the full width at half maximum (FWHM) of each peak.

**Diffuse Reflectance Spectroscopy (DRS).** Composite samples for DRS measurements were prepared by individually grinding  $Sb_2S_3@NTs$ , empty NTs, and bulk  $Sb_2S_3$  crystals with spectroscopic grade potassium bromide (KBr, >99% trace metal basis, Sigma Aldrich). These dilute samples were packed and compressed onto a custommade holder with a transparent quartz window. DRS measurements on these as-prepared samples were performed on a Jasco V-670 spectrometer equipped with a 60 mm integrating sphere (Jasco ISN-923) which operates at a working range of 190-2500 nm. The resulting diffuse reflectance spectra were converted using the Kubelka-Munk function ( $F(R_{\infty})$ ) to approximate the absorbance profiles of the samples.<sup>6</sup>

**Ultraviolet-Visible (UV-Vis) Absorbance Spectroscopy.** Individual suspensions of Sb2S3@BNNTs and empty BNNTs were prepared by sonicating the samples in *i*-PrOH for 5-20 mins. Immediately after sonication, room temperature absorption spectra of the resulting suspensions in the 200 nm to 800 nm range were collected using Agilent Cary 100 UV-Vis spectrophotometer. Pure *i*-PrOH was used as a blank solution for these measurements.

**First-principles density functional theory calculations of the**  $Sb_2S_3@SWCNT_{(21,0)}$  **and**  $Sb_2S_3@SWBNNT_{(21,0)}$ **heterostructures.** DFT calculations were performed to determine the electron density difference map of a single chain of  $Sb_2S_3$  encapsulated within a (21,0) zig-zag SWCNT and SWBNNT. This (n,m) index falls within the suitable diameter  $(-1.6 \text{ nm})$  experimentally observed to house single covalent chains of  $Sb_2S_3$ . All DFT calculations were conducted using the Cambridge Serial Total Energy Package, CASTEP academic 22.11 release.<sup>7</sup> Generalized gradient approximation (GGA) with Perdew-Burke-Ernzerhof (PBE) parametrization and Grimme's DFT-D2 van der Waals force correction were used with on-the-fly generation (OTFG) ultrasoft pseudopotentials.<sup>8,9</sup> Real-space mesh cut-off of 550 eV was used for all DFT calculations. A periodic-boundary-condition (PBC) supercell of a single chain of  $Sb_2S_3$  in a (21,0) SWCNT or SWBNNT was built where the long-axis ([010] direction) of the  $Sb_2S_3$ chain was aligned to the *z*-axis of the CNT. The supercells that were constructed consisted of two-unit cell lengths along the crystallographic  $[010]$  direction of the Sb<sub>2</sub>S<sub>3</sub> crystal structure to minimize the incommensurate lattice mismatch between the  $Sb_2S_3$  and the SWCNT/SWBNNT. The supercell system was then energy minimized using Monkhorst-Pack *k*-point mesh at Gamma until the total energies converged to 10−5 eV per atom and displacements less than 0.001 Å. The electron density difference map was calculated using the optimized geometry with Monkhorst-Pack  $k$ -point mesh of  $1 \times 1 \times 15$ . Bader atomic charges of the systems were calculated using electron density from the final single-point CASTEP calculation with the help of den2VASP and Bader charge analysis  $codes.<sup>10,11</sup>$ 

**X-Ray Photoelectron Spectroscopy (XPS).** XPS samples were prepared by adhering a large quantity of nanotubes (in the case of  $Sb_2S_3@SWCNT$ ,  $Sb_2S_3@BNNT$ , SWCNT, and BNNT) or single crystals of  $Sb_2S_3$  to a plane dual height holder with carbon tape. Spectra were collected on a Kratos Analytical Axis Supra with an Al/Ag monochromated X-ray source and charge neutralizer. Peaks were fit in CasaXPS software using a spline Shirley background and asymmetric Lorentzian peaks. Samples without CNTs were calibrated to adventitious carbon 1s at 284.8 eV, while CNT rich samples were calibrated to the strong graphitic C=C peak at 284.5 eV.<sup>12</sup>

**Thermogravimetric Analysis (TGA).** TGA was collected on a TA Instruments TGA Q500 with a nitrogen purge at a ramp rate of 20 °C/min from room temperature to 1000 °C.

**Electrical Measurements.** Samples were pressed into pellets at 14 MPa between circular disks cut from a weigh boat to aid in liftoff. Rectangular sections  $(Sb_2S_3@BNNT: 1=0.168 cm, A=0.269 x 0.0295 cm = 0.00796 cm^2$ ; empty BNNT: l=0.136 A=0.264 x 0.0242 cm = 0.00637 cm<sup>2</sup>) taken from these pellets and were contacted with pressed indium contacts. Current-voltage (I-V) curves and time-dependent current profiles measured with a forward bias of

10 V were measured using a probe station equipped with a Keithley 4200 SCS semiconductor parameter analyzer. For photocurrent generation measurements, the fabricated devices were illuminated by a Prizmatix 415-nm FC-LED light source at 13 mW/cm<sup>2</sup> controlled by a programmable pulse generator at 0.5 Hz with a 1 s exposure time.

## **2. Supplementary Data and Results**



Figure S1. PXRD of bulk  $Sb_2S_3$  powder used to fill MWCNTs, SWCNTs, and BNNTs in the study.



**Figure S2.** Optical image of gray  $Sb_2S_3$  polycrystals used to fill carbon and boron nitride nanotubes.



Figure S3. Optical image of black  $Sb_2S_3@SWCNTs$  (left) and black empty SWCNTs fibers (right).



Figure S4. Raman peak fit of G-band region of  $Sb_2S_3@SWCNT$  and SWCNT spectrum with negligible shifts and negligible peak broadening.

<b>Sample</b>	<b>Peak Position</b> $\text{(cm}^{-1})$	<b>FWHM</b> $\text{(cm}^{-1})$
$Sb_2S_3@SWCNTG$	$1581.1 \pm 0.4$	$25.7 + 1.3$
<b>SWCNT G-</b>	$1581.7 \pm 0.3$	$24.6 \pm 1.0$
$Sb_2S_3@SWCNTG^+$	$1606.8 \pm 0.1$	$17.2 \pm 0.3$
SWCNT $G^+$	$1606.2 \pm 0.2$	$15.3 \pm 0.2$

**Table S1.** FWHM values of fitted Raman peaks from **Fig. S4**.



Figure S5. Optical images of black  $Sb_2S_3@MWCNT$  (left) and black empty MWCNT powders (right).



Figure S6. Raman spectrum of the low wavenumber region of  $Sb_2S_3@MWCNTs$ ,  $Sb_2S_3$ , and MWCNTs showing both A<sup>g</sup> peaks remain visible despite confinement effects.



Figure S7. Raman spectrum of the high wavenumber region of  $Sb_2S_3@MWCNTs$ ,  $Sb_2S_3$ , and MWCNTs.



Figure S8. DRS of Sb<sub>2</sub>S<sub>3</sub>@MWCNTs, Sb<sub>2</sub>S<sub>3</sub>, and MWCNTs showing that, as with SWCNTs, broadband absorbance of MWCNTs create difficulties when attempting to measure the optical properties of a guest material.



Figure S9. Wide range XPS survey of Sb<sub>2</sub>S<sub>3</sub> in bulk and encapsulated form in BNNTs and SWCNTs. Initially, In powder (\*) was spiked into the sample to serve as an external calibration as some samples contained carbon while others did not. Unfortunately, charge neutralizer overcompensation in insulating samples  $(Sb<sub>2</sub>S<sub>3</sub>$  bulk crystal, empty BNNTs) calibrated to In *3d* displayed erratic values several eV above literature. Instead, following literature procedures, samples that did not contain graphitic carbon (a-Sb<sub>2</sub>S<sub>3</sub>@BNNT, Sb<sub>2</sub>S<sub>3</sub>, BNNTs) were calibrated to the C *1s* of the adventitious carbon peak at 284.8 eV while graphitic carbon-containing samples (c-Sb<sub>2</sub>S<sub>3</sub>@SWCNT, empty SWCNTs) were calibrated to the sharp C *1s* peak at 284.5 eV.<sup>12</sup> This calibration appeared to arrive at the most reasonable values and is consistent with literature for fitting of adventitious and graphitic carbon samples.



**Figure S10.** Regional XPS of Sb *3d* and S *2p* peaks. Sb *3d5/2* peaks overlap with O *1s*, which is colored red for clarity. It can be observed that only one Sb<sup>3+</sup> environment is present in both the @BNNT and @SWCNT samples when compared to the three Sb types in bulk  $Sb_2S_3$ , which contains a prominent peak of  $Sb_2S_3$  but also two Sb oxide peaks, one for  $Sb_2O_3$  and one for  $Sb_2O_5$ . This indicates the nanotubes may offer some protection against oxidation at room temperature. Only one S environment is observed in a-Sb<sub>2</sub>S<sub>3</sub>@BNNT, c-Sb<sub>2</sub>S<sub>3</sub>@SWCNT, and bulk Sb<sub>2</sub>S<sub>3</sub>. Empty SWCNTs showed a minor S impurity peak likely from cross contamination during sample preparation.

$Sb_2S_3@BNNT$	Sb 3d 5/2	Sb 3d 3/2	S 2p 3/2	S 2p 1/2
Peak position (eV)	529.97	539.40	161.95	163.20
FWHM (eV)	1.3	1.3	1.24	1.24
Area	10580.5	7053.67	1209.82	604.91
Sb <sub>2</sub> S <sub>3</sub> @SWCNT	Sb 3d 5/2	Sb 3d 3/2	S 2p 3/2	S 2p 1/2
Peak position (eV)	529.95	539.31	161.67	162.92
FWHM (eV)	1.26	1.26	1.05	1.05
Area	41908.22	27938.81	4137.23	2068.61
$Sb_2S_3$ Bulk	Sb 3d 5/2	Sb 3d 3/2	S 2p 3/2	$S 2p \frac{1}{2}$
Peak position (eV)	529.72	539.08	161.57	162.81
			0.94	0.94
FWHM (eV)	0.95	0.95		
Area	64530.09	42589.86	7604.04	3802.02
$Sb2O3$ (from bulk)	Sb 3d 5/2	Sb 3d 3/2		
Peak position (eV)	530.54	539.79		
FWHM (eV)	1.04	1.04		
Area	17096.58	11283.74		
$Sb2O5$ (from bulk)	Sb 3d 5/2	Sb 3d 3/2		
Peak position (eV)	531.63	540.89		
FWHM (eV)	0.92	0.92		

**Table S2** Fit XPS values of Sb 3d and S 2p.



**Figure S11.** TGA curves of SWCNTs, c-Sb<sub>2</sub>S<sub>3</sub>@SWCNTs, BNNTs, a-Sb<sub>2</sub>S<sub>3</sub>@BNNTs, and bulk Sb<sub>2</sub>S<sub>3</sub> with nitrogen purge.



**Figure S12.** Representative HRTEM images of empty BNNTs. (A) Purified and treated (to open ends) BNNTs, which contained defects, BN aggregate filling within BNNTs, and a high quantity of non-nanotube BN outside of the nanotubes. (B) High purity BNNTs exposed to a proprietary purification process (BNNT LLC) much longer than the nanotubes used in this study with no non-nanotube material remaining outside the BNNTs. BN aggregates remained inside the nanotubes. (C) High purity nanotubes from B which were additionally exposed to calcination at 800 °C for 5 hours, after which BN aggregate filling remained. (D) High purity nanotubes from B which were first washed in aqua regia for 5 hours and subsequently washed thoroughly with water followed by calcination at 800 °C for 5 hours. BN aggregate filling remained after this process. These aggregates likely act as a defect and is responsible for a significant portion of the  $Sb_2S_3$ -filled samples being a- $Sb_2S_3$ .



Figure S13. Conductivity measurements of Sb<sub>2</sub>S<sub>3</sub>@BNNT and BNNT pressed pellets. Sb<sub>2</sub>S<sub>3</sub>@BNNT: l=0.168 cm, A=0.269 x 0.0295 cm = 0.00796 cm<sup>2</sup>; empty BNNT: l=0.136 A=0.264 x 0.0242 cm = 0.00637 cm<sup>2</sup>

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